



SHEET 1 OF 2

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		PATENT DOCKET NO. 249420US2		SERIAL NO. 10/784,932	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Kazuo NAKAJIMA, et al.		GROUP 1753	
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ADD	AA	N. USAMI, et al., Japan-Australia Workshop on Advanced Materials, Institute for Materials Research (IMR), pages xiv and 16, "ADVANCED SI-BASED MATERIALS FOR SOLAR CELL APPLICATIONS: MULTICRYSTALLINE-SiGe WITH MICROSCOPIC COMPOSITIONAL DISTRIBUTION AND VERTICALLY STACKED-Ge ISLANDS", January 15-19, 2004					
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						<input checked="" type="checkbox"/> Additional References sheet(s) attached	
Examiner						Date Considered 7/14/05	
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EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
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	AB						
	AC						
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	AE						
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	AM						
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FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION	
					YES	NO
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	AQ					
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	AT					
	AU					
	AV					

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